

NTE585 Silicon Rectifier Diode Schottky Barrier, Fast Switching

Features:

- Low Switching Noise
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Capability

Maximum RMS Voltage	28V
Maximum DC Blocking Voltage	40V
Maximum Average Forward Rectified Current (375" . (9.5mm) lead length at $T_L = +90^{\circ}$	°C) 1.0A
Peak Forward Surge Current	
(8.3ms single half sine–wave superimposed on rated load $T_L = +70^{\circ}C$)	25A
Maximum Forward Voltage at 1.0A DC	60V
Maximum Forward Voltage at 3.1A DC	90V
Maximum Average Reverse Current at Peak Reverse Voltage	
$T_A = +25$ °C	1.0mA
$T_A = +100$ °C	10mA
Typical Thermal Resistance, Junction–to–Ambient (Note 1), R _{thJA}	80°C/W
Typical Junction Capacitance (Note 2)	110pF
Operating Junction Temperature Range T _J	5° to +125°C

Note 1. Thermal Resistance Junction to Ambient Vertical PC Board Mounting, 0.5" (12.7mm) Lead Length.

Note 2. Measured at 1MHz and applied reverse voltage of 4.0 Volts.

